

### Holographic doped Mott insulator

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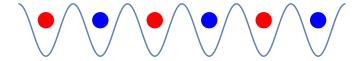
#### References

arXiv:1512.02465 arXiv:1701.04625 arXiv:1708.08306 arXiv:1710.XXXXX arXiv:1710.XXXXX

Tomas Andrade, **A.K.**Tomas Andrade, **A.K.**T.Andrade, M. Baggioli **A.K** and N. Poovuttikul T.Andrade, **A.K.**, K.Schalm and J.Zaanen **A.K.** 

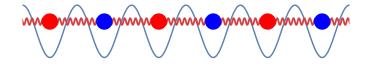
#### Mott insulator

Take the periodic lattice, half-filled with electrons



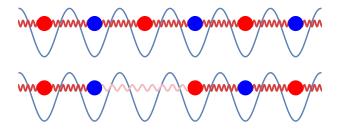
#### Mott insulator

#### Include interaction between electrons



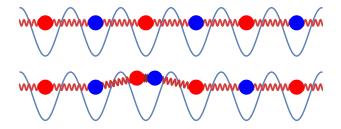
#### Doped Mott insulator

#### Doping either removes an electron



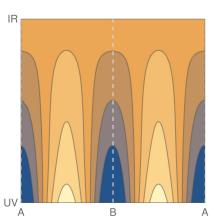
#### Doped Mott insulator

#### Or adds an electron



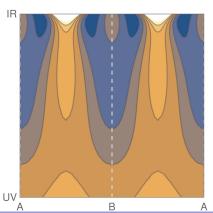
Take the ionic lattice

$$\mu(x) = \mu_0 \left( 1 + A \cos(kx) \right)$$

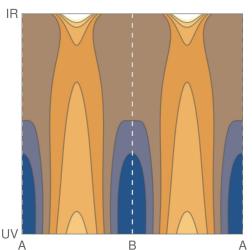


Take the spontaneous inhomogeneous structure

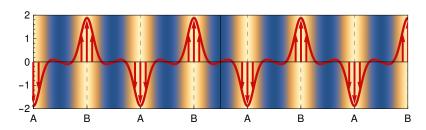
$$S = \int d^4x \sqrt{-g} \left( R - \frac{1}{2} (\partial \psi)^2 - \frac{\tau(\psi)}{4} F^2 - V(\psi) \right) - \frac{1}{2} \int \vartheta(\psi) F \wedge F$$



They form commensurately locked state

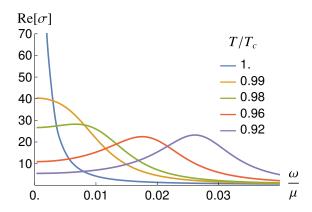


The locked state features the staggered current pattern



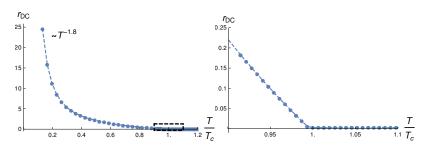
#### Metal - insulator crossover

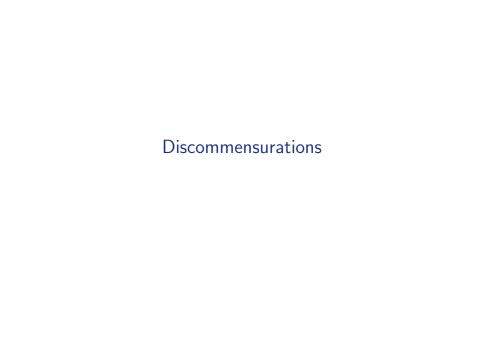
Drude peak is pinned at  $T_c$ 



#### Metal - insulator crossover

#### At low temperature this is an algebraic insulator





#### Commensurate fractions

Suppose lattice has momentum k and period  $\lambda_k$ And spontaneous wave has momentum p and period  $\lambda_p$ 

The state with commensurate fraction:

$$\frac{N_p}{N_k} = \frac{p}{k}$$

Has a unit cell of the size

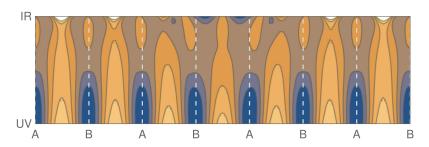
$$\lambda_{\Sigma} = N_{p}\lambda_{p} = N_{k}\lambda_{k}$$

Almost commensurate state has  $N_p = N_k + 1$ 

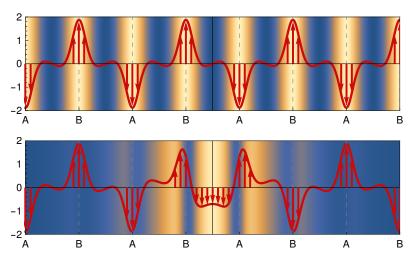
$$\frac{N_p}{N_k} = 1 + \frac{1}{N_k}$$

One discommensuration per  $N_k$  lattice units

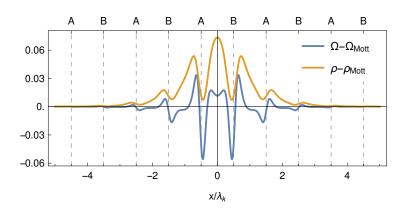
The mismatch of the periods is accounted for in the core.



Discommensuration is a domain wall in the staggered current



Discommensuration is a soliton with finite size and positive charge



## Doping the holographic Mott insulator

#### Doping

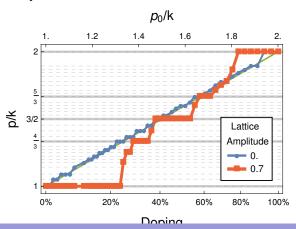
By **doping** one changes the charge density. The excess charge can be stored in discommensurations.

State with finite density of discommensurations  $(n_d)$  is a *higher commensurate state* 

$$\frac{N_p}{N_k} = 1 + \frac{N_d}{N_k} \equiv 1 + n_d$$

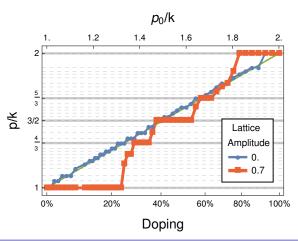
#### Higher commensurate points

Higher commensurate states are assumed due to commensurate lock in when the periods of pure spontaneous wave and the lattice are significantly different.



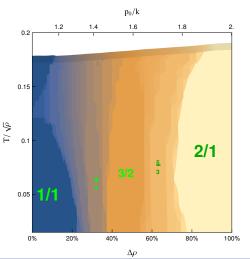
#### Higher commensurate points

Keeping the lattice constant fixed one can change the period of spontaneous structure by tuning  $\mu_0$  or charge density (doping)



#### Phase diagram of commensurate states

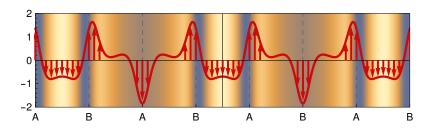
Commensurate lock in is stronger at lower temperature



#### Discommensuration lattices

Doped Mott insulator has finite density of discommensurations which arrange themselves as periodic lattices.

$$\frac{N_p}{N_k} = 1 + \frac{1}{3} = \frac{4}{3}$$



#### Conclusion

- Holographic Mott insulator is the lowest order commensurate state of the spontaneous wave.
- Doping promotes higher commensurate states and discommensurations
- Discommensurations are similar to spin stripes observed in reality
- Higher commensurate lock in makes discommensuration lattices robust against doping.